





UNITED STATES PATENT AND TRADEMARK OFFICE



UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER OF PATENTS AND TRADEMARKS Washington, D.C. 20231 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/557,961	04/25/2000	Kunihiro Takatani	245402001600	8878
7	590 02/13/2002			
Barry E Bretschneider Morrison & Foerster LLP 2000 Pennsylvania Avenue NW			EXAMINER	
			KANG, DONGHEE	
Washington, DC 20006-1888			ART UNIT	PAPER NUMBER
			2811	
			DATE MAILED: 02/13/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

•		···				
Offic Action Summary		Application No.	Applicant(s)			
		09/557,961	TAKATANI, KUNIHIRO			
		Examiner	Art Unit			
		Donghee Kang	2811			
- Period fo	- The MAILING DATE of this communication app r Reply	ears on the cover sheet with the	c rrespondence address			
THE N - Exten after S - If the - If NO - Failur - Any re	DRTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. sions of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period we to reply within the set or extended period for reply will, by statute, eply received by the Office later than three months after the mailing d patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be to within the statutory minimum of thirty (30) da will apply and will expire SIX (6) MONTHS fror cause the application to become ABANDON	mely filed ys will be considered timely. n the mailing date of this communication. ED (35 U.S.C. § 133).			
1) 🖂	Responsive to communication(s) filed on 17 S	September 2001 .				
2a)⊠	, , , , , , , , , , , , , , , , , , , ,	is action is non-final.				
3)						
Disposition	on of Claims					
4)⊠ Claim(s) <u>1-5 and 8-11</u> is/are pending in the application.						
4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1-5 and 8-11</u> is/are rejected.						
7)	7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
9)[] 7	The specification is objected to by the Examine	r.				
10)[] 7	Γhe drawing(s) filed on is/are: a)□ accep	oted or b) objected to by the Exa	aminer.			
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11)[] 7	The proposed drawing correction filed on		roved by the Examiner.			
If approved, corrected drawings are required in reply to this Office action.						
12) The oath or declaration is objected to by the Examiner.						
Priority u	inder 35 U.S.C. §§ 119 and 120					
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) All b) Some * c) None of:						
	1. Certified copies of the priority documents	s have been received.				
	2. Certified copies of the priority documents have been received in Application No					
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).						
a) ☐ The translation of the foreign language provisional application has been received. 15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachmen	t(s) _/		•			
2) Notic	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informa	ry (PTO-413) Paper No(s) I Patent Application (PTO-152)			



Art Unit: 2811

DETAILED ACTION

Acknowledgement

1. Applicant's Amendment and Response to Paper No.8 has been entered and made of record. Claims 8-11 have been added. Therefore, claims 1-5 and 8-11 are pending in this office action.

Claim Rejections - 35 USC § 112

- 2. The following is a quotation of the first paragraph of 35 U.S.C. 112:
 - The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.
- 3. Claims **8-11** are rejected under 35 U.S.C. 112, first paragraph, as containing subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention.

The specification recites the first metal electrode layer includes at least one selected from a first metal group of Ti, Hf, Zr, V, Nb, Ta, Cr, W and Sc. There is no support in the specification for *first electrode layer including at least one metal having a* free energy of nitride formation of less –51 kcal/mol as recited claim 8.

Claim Rejections - 35 USC § 102

- (e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.
- 4. Claim 1 is rejected under 35 U.S.C. 102(e) as being anticipated by Okazaki (US 5,990,500).



Application/Control Number: 09/557,961

Art Unit: 2811

Okazaki discloses an electrode structure on a p-type III group nitride semiconductor layer comprising first, second and third electrode layers successively stacked on said semiconductor layer, said first electrode layer including a Ti, said second electrode layer including a Pd, and said third electrode layer including Au. See Col.7, line 45 – Col.8, line 58 and Fig.5A.

Claim Rejections - 35 USC § 103

- 5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 6. Claims **2-5** are rejected under 35 U.S.C. 103(a) as being unpatentable over Okazaki (US 5,990,500)

Regarding claims **2-3**, Okazaki does not explicitly disclose in Fig.5A the first and second electrode layers have a thickness in a range from 1 to 500 nm. However, Okazaki discloses the first and second electrode layers have a thickness not larger than 5 nm, which is in the claimed ranges in the other embodiment (Col.5, lines 4 - 30). The selection of thickness of various layers in device is an obvious design choice, therefore held within ordinary skills in the art.

Regarding claim **4**, Okazaki does not explicitly disclose the third electrode layer has a thickness of 50 nm or more. However, Okazaki discloses the third electrode layer has a thickness not thicker than 10 nm, which is in the claimed ranges in other





Arf Unit: 2811

embodiment (Col.5, lines 4-30). The selection of thickness of various layers in device is an obvious design choice, therefore held within ordinary skills in the art.

Regarding claim **5**, Okazaki teaches all claimed invention, as applied to claim 1 above, except for first electrode layer includes a nitride and a compound of Ga-Ni. In view of this invention, the Ti-N compound and the Ga-Ni compound were formed in first electrode layer by reaction during the thermal annealing process as described in specification where the N and Ga are supplied from GaN layer (page 6, lines 1-11). The first electrode in Okazaki's metal electrode structure may also include a Ti-N and Ga-Ni compound because the Okazaki's metal electrode structure is also treated by thermal process (Fig.5B) and the structure of Okazaki is identical to the claimed structure. Thus, the claimed structure is taken to be in the least obvious over Morimoto.

Response to Arguments

7. Applicant's arguments with respect to claims 1-5 and 8-11 have been considered but are most in view of the new ground(s) of rejection.

Conclusion

8. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any

Application/Control Number: 09/557,961

Art Unit: 2811

extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Donghee Kang whose telephone number is 703-305-9147. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on 703-308-2772. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

TOM THOMAS
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800

Donghee Kang, Ph.D. November 20, 2001